

SANYO Semiconductors DATA SHEET

EFC4615R — General-Purpose Switching Device Applications

Features

- 2.5V drive
- · Best suited for LiB charging and discharging switch
- · Common-drain type

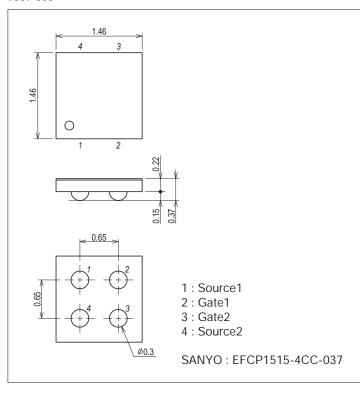
Specifications

Absolute Maximum Ratings at Ta=25°C

| Parameter | Symbol | Conditions | Ratings | Unit |
|--------------------------|------------------|--|-------------|------|
| Source-to-Source Voltage | V _{SSS} | | 24 | V |
| Gate-to-Source Voltage | VGSS | | ±12 | V |
| Source Current (DC) | IS | | 6 | А |
| Source Current (Pulse) | ISP | PW≤10μs, duty cycle≤1% | 60 | А |
| Total Dissipation | PT | When mounted on ceramic substrate (5000mm ² x0.8mm) | 1.6 | W |
| Channel Temperature | Tch | | 150 | °C |
| Storage Temperature | Tstg | | -55 to +150 | °C |

Package Dimensions

unit : mm (typ) 7067-001



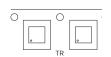
Product & Package Information

• Package : EFCP

• JEITA, JEDEC :-

• Minimum Packing Quantity : 5,000 pcs./reel

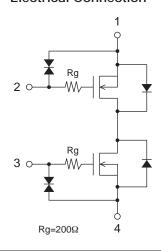
Taping Type: TR



Marking



Electrical Connection

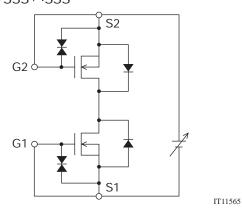


Electrical Characteristics at Ta=25°C

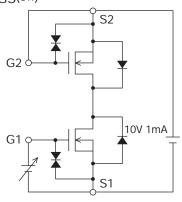
| Parameter | Symbol | Conditions | | Ratings | | | 11-14 |
|---|-----------------------|---|----------------|---------|-----|-----|-------|
| | | | | min | typ | max | Unit |
| Source-to-Source Breakdown Voltage | V(BR)SSS | IS=1mA, VGS=0V | Test Circuit 1 | 24 | | | V |
| Zero-Gate Voltage Source Current | ISSS | VSS=20V, VGS=0V | Test Circuit 1 | | | 1 | μΑ |
| Gate-to-Source Leakage Current | IGSS | VGS=±8V, VSS=0V | Test Circuit 2 | | | ±10 | μΑ |
| Cutoff Voltage | VGS(off) | VSS=10V, IS=1mA | Test Circuit 3 | 0.5 | | 1.3 | V |
| Forward Transfer Admittance | yfs | VSS=10V, IS=3A | Test Circuit 4 | | 5.4 | | S |
| Static Source-to-Source On-State Resistance | R _{SS} (on)1 | I _S =3A, V _{GS} =4.5V | Test Circuit 5 | 19 | 27 | 31 | mΩ |
| | R _{SS} (on)2 | IS=3A, VGS=4.0V | Test Circuit 5 | 21 | 28 | 33 | mΩ |
| | RSS(on)3 | I _S =3A, V _{GS} =3.1V | Test Circuit 5 | 24 | 33 | 44 | mΩ |
| | RSS(on)4 | IS=3A, VGS=2.5V | Test Circuit 5 | 28 | 39 | 52 | mΩ |
| Turn-ON Delay Time | t _d (on) | See specified Test Circuit. | Test Circuit 7 | | 13 | | ns |
| Rise Time | t _r | See specified Test Circuit. | Test Circuit 7 | | 235 | | ns |
| Turn-OFF Delay Time | t _d (off) | See specified Test Circuit. | Test Circuit 7 | | 335 | | ns |
| Fall Time | tf | See specified Test Circuit. | Test Circuit 7 | | 360 | | ns |
| Total Gate Charge | Qg | VSS=10V, VGS=4.5V, IS=6A | | | 8.8 | | nC |
| Forward Source-to-Source Voltage | V _F (S-S) | I _S =6A, V _{GS} =0V | Test Circuit 6 | | 1 | 1.2 | V |

Test circuits are example of measuring FET1 side



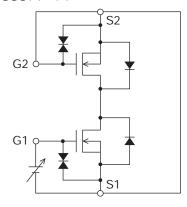


Test Circuit 3 VGS(off)



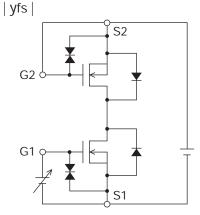
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Test Circuit 2 IGSS(+) / (--)

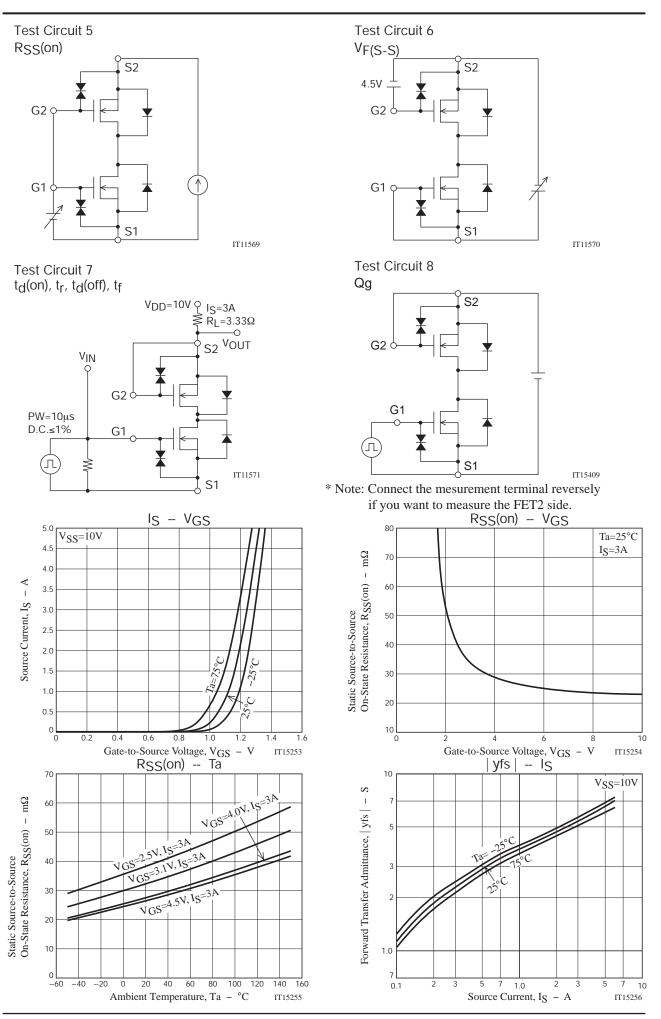


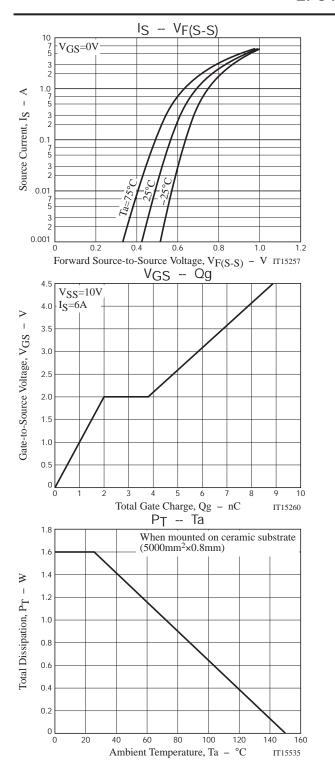
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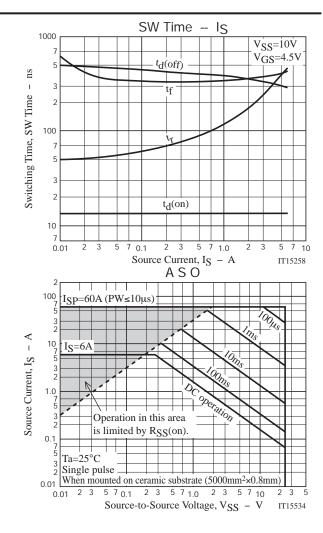
Test Circuit 4



* Note: Connect the mesurement terminal reversely if you want to measure the FET2 side.







Note on usage: Since the EFC4615R is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

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